

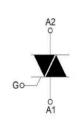
Description

The Z0107MN5AA4 provide high dv/dt rate with strong resistance to electromagnetic interface. They are especially recommended for use on residual current circuit breaker, straight hair, igniter etc.



Main Features

symbol	value	unit
I _{T(RMS)}	1.0	Α
I _{GT}	5	mA
V _{DRM} /V _{RRM}	600	V



Absolute Maximum Ratings

Symbol	Parameter	Conditions	Value	Unit
VDRM /VRRM	repetitive peak off-state voltage		600	V
IT(RMS)	RMS on-state current		1	Α
Non repetitive surge peak		t = 20ms T _j = 25°C	10	
Ітѕм	on-state current	t = 16.7ms T _j =25℃	8	Α
l2t	I ² t for fusing	t = 10 ms	1	A ² s
dl/dt	Critical-rate of rise of I II III commutation current IV	I _G =2I _{GT} tr≤100ns F=120Hz	50 10	A/us
Igм	Peak Gate Current	$T_j = 125^{\circ}C \text{ tp} = 20\mu s$	0.3	Α
VgM	Peak gate voltage	T _j =125 °C	1	V
Рсм	Peak gate power	T _j =125 °C	0.8	W
P _G (AV)	Average Gate Power Dissipation	T _j =125 °C	0.4	W
Tj	Junction Temperature	-	125	°C
T _{stg}	Storage Temperature	-	-40 ~ 150	°C

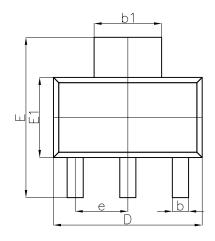


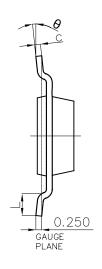
Electrical Characteristics (T_j =25°C unless otherwise specified)

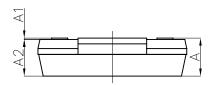
Parameter		Symbol	Test con	ditions	Min	Тур	Max	Unit
Repetitive Peak Off-State Current		IDRM,IRRM	V _{DRM} =V _{RRM} T _j =25°C				5	μΑ
Repetitive Peak Reverse Current			VDRM=VRRM T _j =125°C				1	mA
Gate non-trigger voltage		V_{GD}	V _D = 1/2V _{DRM}		0.2			V
On-state voltage V _{TM} I _T = 1A,t _p		I _T = 1A,t _p =380us				1.65	V	
Gate trigger current		lgт	\/p=12\/ P. =1000				5	mA
	IV	IGI	$V_D=12V, R_L=100\Omega$				7	1117 (
	I	V _{GT}	T ₂ (+), G(+)			0.8	2	
Gate trigger voltage	II		T ₂ (+), G(-)	V _D =12V		8.0	2	V
	III		T ₂ (-), G(-)	R _L =100Ω		0.8	2	V
	IV		T ₂ (-), G(+)			8.0	2.5	
Holding current		Ін	VD=12V,IGT=100mA				30	mA
Critical-rate of rise of commutation voltage		dV/dt	V _{DM} =67%V _{DRM} Gate open Tj =125°C				50	V/us
		d v/dt						
Rate of change of commutating voltage		(dl/dt)c	V _{DM} =400V, T _j =125 °C				20	V/us
		(ui/ut)c	(dl/dt)c=5.4A/ms Gate open					
Turn-on time		t _{gt}	I _{TM} = 16A , V _{DM} = V _{DRM(MAX)} I _G = 0.1A, dI _G dt = 5A/uS				2	us



SOT-223 Package Outline Dimensions







Symbol	Dimensions Ir	n Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
Α		1.800		0.071	
A1	0.020	0.100	0.001	0.004	
A2	1.500	1.700	0.059	0.067	
b	0.660	0.840	0.026	0.033	
b1	2.900	3.100	0.114	0.122	
С	0.230	0.350	0.009	0.014	
D	6.300	6.700	0.248	0.264	
E	6.700	7.300	0.264	0.287	
E1	3.300	3.700	0.130	0.146	
е	2.300(BSC)		0.091(BSC)		
L	0.750		0.030		
θ	0°	10°	0°	10°	



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